10.1 Creation of new materials
10.2 Spin torque, spin current, circuits, and measurement technologies
10.3 Giant magnetoresistance (GMR), tunnel magnetoresistance (TMR) and magnetic recording technologies
10.4 Semiconductors, organic, optical, and quantum spintronics

4:00 PM - 6:00 PM

17p-PB3-33 A study of FANOUT function in current driven spin memory and logic

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Keywords: spin logic, domain wall